

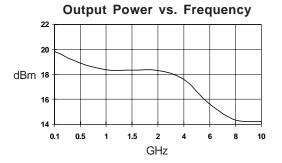
Product Description

Stanford Microdevices' SNA-476 is a GaAs monolithic broadband amplifier (MMIC) housed in a low-cost surface mountable stripline ceramic package. This amplifier provides 13dB of gain when biased at 70mA and 5.0V.

External DC decoupling capacitors determine low frequency response. The use of an external resistor allows for bias flexibility and stability.

These unconditionally stable amplifiers are designed for use as general purpose 50 ohm gain blocks. Also available in chip form (SNA-400), its small size (0.4mm x 0.4mm) and gold metallization, make it an ideal choice for use in hybrid circuits.

The SNA-476 is available in tape and reel at 1000, 3000 and 5000 devices per reel.



SNA-476

DC-8 GHz, Cascadable GaAs MMIC Amplifier



Product Features

- Cascadable 50 Ohm Gain Block
- 13dB Gain, +17dBm P1dB
- 1.5:1 Input and Output VSWR
- Operates From Single Supply
- Low Cost Stripline Mount Ceramic Package
- Hermetically Sealed

Applications

- Narrow and Broadband Linear Amplifiers
- Commercial and Industrial Applications

Electrical Specifications at Ta = 25C

Symbol	Parameters: Test Conditions: Id = 70 m A, Z ₀ = 50 O hm s		Units	M in.	Тур.	Мах.
G _P	Small Signal Power Gain	f = 0.1-2.0 G H z f = 2.0-6.0 G H z f = 6.0-8.0 G H z	d B d B d B	11.0 10.0 9.0	13.0 12.0 11.0	
G _F	Gain Flatness	f = 0.1-6.0 G H z	d B		+/- 1.0	
B W 3 d B	3dB Bandwidth		GHz		8.0	
P _{1 d B}	Output Power at 1dB Compression	f = 2.0 G H z	d B m		17.0	
NF	Noise Figure	f = 2.0 G H z	d B		5.5	6.0
V S W R	Input / Output	f = 0.1-8.0 G H z			1.5:1	
IP ₃	Third Order Intercept Point	f = 2.0 G H z	d B m		34.0	
T _D	Group Delay	f = 2.0 G H z	psec		120	
IS O L	Reverse Isolation	f = 0.1-8.0 G H z	d B		18.0	
V D	Device Voltage		V	4.3	5.0	5 .7
d G /d T	Device Gain Temperature Coefficient		d B /d e g C		-0.0027	
d V /d T	Device Voltage Temperature Coefficient		m V/degC		-5.0	

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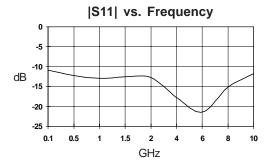
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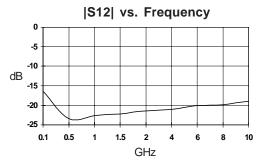
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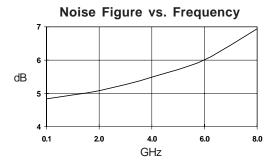


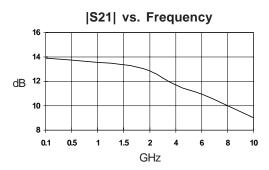
SNA-476 DC-8 GHz Cascadable MMIC Amplifier

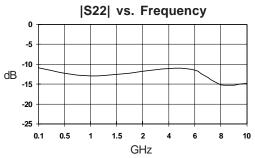
Typical Performance at 25° C (Vds = 5.0V, Ids = 70mA)

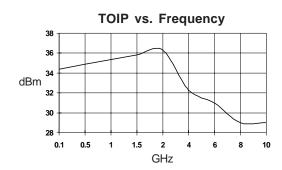












Typical S-Parameters Vds = 5.0V, Id = 70mA

Freq GHz	S11	S11 Ang	S21	S21 Ang	S12	S12 Ang	S22	S22 Ang
.100	0.205	148	5.268	176	0.112	0	0.141	160
.250	0.233	136	5.124	166	0.111	9	0.157	150
.500	0.282	120	4.891	139	0.119	-29	0.185	121
1.00	0.295	64	4.793	101	0.118	-55	0.207	68
1.50	0.302	6	4.746	60	0.117	-87	0.227	13
2.00	0.290	-46	4.774	21	0.117	-113	0.231	-37
4.00	0.150	74	3.740	57	0.104	7	0.222	-90
6.00	0.164	-52	3.331	61	0.151	-2	0.130	1
8.00	0.275	161	2.973	-109	0.100	-115	0.190	147

(S-Parameters include the effects of two 1.0 mil diameter bond wires, each 20 mils long, connected to the gate and drain pads on the die)



SNA-476 DC-8 GHz Cascadable MMIC Amplifier

Absolute Maximum Ratings

Parameter	Absolute Maximum
Device Current	100m A
Power Dissipation	560mW
RF Input Power	200mW
Junction Temperature	+200C
Operating Temperature	-45C to +85C
Storage Temperature	-65C to +150C

Notes:

MTTF vs. Temperature @ Id = 70mA

<u> </u>					
Lead Temperature	Junction Temperature	MTTF (hrs)			
+45C	+155C	1000000			
+80C	+190C	100000			
+110C	+220C	10000			

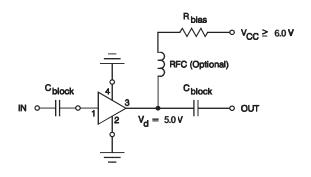
Thermal Resistance (Lead-Junction): 315° C/W

Part Number Ordering Information

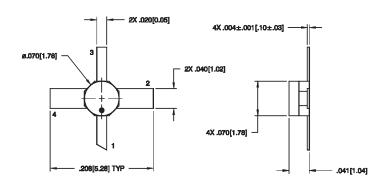
Part Number	Devices Per Reel	Reel Size
SNA-476-TR1	1000	7"
SNA-476-TR2	3000	13"
SNA-476-TR3	5000	13"

Recommended Bias Resistor Values						
Supply Voltage(Vs)	5V	7.5V	9V	12V	15V	20V
Rbias (Ohms)	*	36	57	100	143	214

^{*} Needs active biasing for constant current source

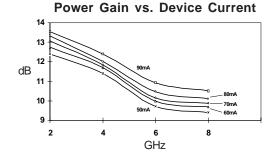


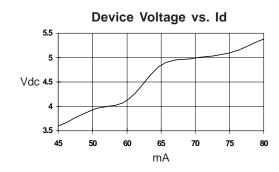
Typical Biasing Configuration



Pin Designation			
1	RF in		
2	GND		
3	RF out and Bias		
4	GND		

Typical Performance at 25° C





Phone: (800) SMI-MMIC

^{1.} Operation of this device above any one of these parameters may cause permanent damage.